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Laipeng Yan, Zhanqiu Tan, Gang Ji, Zhiqiang Li, Genlian Fan, D. Schryvers,  
Aidang Shan, Di Zhang

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A quantitative method to characterize the  $\text{Al}_4\text{C}_3$ -formed interfacial  
reaction: the case study of MWCNT/Al composites

Laipeng Yan <sup>a</sup>, Zhanqiu Tan <sup>a</sup>, Gang Ji <sup>b</sup>, Zhiqiang Li <sup>a,\*</sup>, Genlian Fan <sup>a</sup>, D. Schryvers <sup>c</sup>, Aidang Shan <sup>d,e</sup>, Di Zhang <sup>a</sup>

<sup>a</sup> State Key Laboratory of Metal Matrix Composites, Shanghai Jiao Tong University, Shanghai 200240, China

<sup>b</sup> Unité Matériaux et Transformations (UMET), CNRS UMR 8207, Université Lille 1, 59655 Villeneuve d'Ascq, France

<sup>c</sup> Electron Microscopy for Materials Science (EMAT), University of Antwerp Groenenborgerlaan 171, 2020 Antwerp, Belgium

<sup>d</sup> School of Materials Science and Engineering, Shanghai Jiao Tong University, Shanghai 200240, China

<sup>e</sup> School of Environmental Science and Engineering, Shanghai Jiao Tong University, Shanghai 200240, China

### Abstract

The  $\text{Al}_4\text{C}_3$ -formed interfacial reaction plays an important role in tuning the mechanical and thermal properties of carbon/aluminum (C/Al) composites reinforced with carbonaceous materials such as multi-wall carbon nanotube (MWCNT) and graphene nanosheet. In terms of the hydrolysis nature of  $\text{Al}_4\text{C}_3$ , an electrochemical dissolution method was developed to quantitatively characterize the extent of C/Al interfacial reaction, which involves dissolving the composite samples in alkaline solution first, then collecting and measuring the  $\text{CH}_4$  gas released by  $\text{Al}_4\text{C}_3$  hydrolysis with a gas chromatograph. Through a case study with powder metallurgy fabricated 2.0 wt.% MWCNT/Al composites, the detectability limit of the proposed method is 0.4 wt.%  $\text{Al}_4\text{C}_3$ , corresponding to 5 % extent of interfacial reaction with a measurement error of  $\pm 3$  %. And then, with the already known MWCNT/Al reaction extent vs different sintering temperature and time, the reaction kinetics with an activation energy of  $281 \text{ kJ mol}^{-1}$  was successfully derived. Therefore, this rapid, sensitive, accurate method supplies an useful tool to optimize the processing and properties of all kinds of C/Al composites via interface design/control.

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\* Corresponding author. Tel.: +86 21 5474 5872. Fax: +86 21 3420 2749  
E-mail address: lizhq@sjtu.edu.cn (Z. Li) , tanzhanqiu@sjtu.edu.cn (Z. Tan).

**Keywords:** MWCNT/Al composite; Interfacial reaction; Aluminum carbide; Electrochemical dissolution.

## 1. Introduction

Carbon/Aluminum (C/Al) composites reinforced with carbonaceous materials such as multi-wall carbon nanotube (MWCNT), graphene nanosheet, carbon fiber, diamond/graphite particle, are promising candidates for next-generation metallic composites due to their excellent mechanical and thermal properties [1-6]. In addition to the spatial distribution of the reinforcements, the interfacial configurations, including chemistry, structure and bonding, also play an important role in determining the global properties of all kinds of the C/Al composites [7-9]. An ideal C/Al interface should not only transfer the applied load from the matrix to the reinforcements, but also facilitate the thermal exchange by reducing the interfacial thermal resistance [10-12]. In fact, the chemical reaction between Al matrix and carbonaceous reinforcements, in terms of the equation  $4\text{Al}+3\text{C}\rightarrow\text{Al}_4\text{C}_3$ , is thermodynamically favorable both in casting and powder metallurgy processing routes. Many literatures reported that the formation of a ceramic  $\text{Al}_4\text{C}_3$  phase at the C/Al interface can improve interfacial bonding to some extent [13, 14]. However, the formation of excessive  $\text{Al}_4\text{C}_3$  is considered to be harmful due to its intrinsic brittleness, low thermal conductivity and strong tendency of hydrolysis [15, 16]. In other words, the properties and reliability of the C/Al composites significantly depend on the extent of the  $\text{Al}_4\text{C}_3$ -formed interfacial reaction. Therefore, it becomes a critical issue to correlate the properties with various processing conditions and interfacial reaction extent.

But it is embarrassing that so far there is no efficient, quantitative method to evaluate the extent of C/Al interfacial reaction. Usually, the  $\text{Al}_4\text{C}_3$  resulted from interfacial reaction has been characterized either by X-ray diffraction (XRD) and Raman spectroscopy (RS), or by scanning electron microscopy (SEM) and transmission electron microscopy (TEM) [17]. XRD and RS are semi-quantitative methods and can only be used to detect  $\text{Al}_4\text{C}_3$  when its content is higher than 4-5 wt.%. Comparatively, SEM and TEM allow one to directly observe the morphology of  $\text{Al}_4\text{C}_3$  product, but there is no statistical significance considering the localized, limited field of view in SEM and TEM. In this regard, Lee *et al.* [18] and Monje *et al.* [19] attempted to extract the  $\text{Al}_4\text{C}_3$  particles from SiC/Al and diamond/Al composites by electrochemically dissolving the Al matrix, and then gave a qualitative comparison of the interfacial reaction extent by direct SEM observation. Hence, none of the above-mentioned techniques are viable for quantitatively measuring the amount of  $\text{Al}_4\text{C}_3$  formed in the C/Al composites.

The most feasible method ever reported is to deduce the content of  $\text{Al}_4\text{C}_3$  from the amount of methane ( $\text{CH}_4$ ) released from the hydrolysis of  $\text{Al}_4\text{C}_3$  [15]. This method involved dissolving diamond/Al sample (~0.5 g) in a 20 % HCl solution and then analytically measured the  $\text{CH}_4$  collection by a gas chromatograph [15]. This chemical dissolution-gas chromatography method supplied a possible solution for quantitatively characterizing the extent of C/Al interfacial reaction. Since no concrete practical experimental set-up was presented in reference [15] and elsewhere, here we have improved this method in the following aspects: (1) Electrochemical dissolution in

alkaline solution was used to accelerate the dissolving of C/Al composite samples and the hydrolysis of  $Al_4C_3$ ; (2) C/Al samples of larger size, e.g. ~1.5 g, was adopted and thus enough  $CH_4$  gas for measurement could be generated in reasonable time. As results, C/Al composites with very low reinforcement content and/or very low interfacial reaction extent could be characterized with reliable accuracy. This is of great importance because our previous studies have demonstrated that in MWCNT/Al [1, 20], diamond/Al [21, 22] and graphite flakes/Al-Si composites [23], better mechanical and thermal properties always occur with very low  $Al_4C_3$  content. As a case study, powder metallurgy fabricated 2.0 wt.% MWCNT/Al composites have been used to validate the newly developed method. The detectability limit (i.e. the minimum reaction extent could be detected) and accuracy were shown to be around 5 % and  $\pm 3$  %, respectively, which were far beyond the ability of XRD and RS.

## 2. Material and methods

Aluminum powders (99.9 % in purity) with an average particle size of 30  $\mu m$  were used as the matrix material. MWCNTs (99.9 % in purity) of about 150 nm in diameter and of 10~20  $\mu m$  in length were used as the reinforcement. The mass fraction of MWCNTs in the composites was 2.0 wt.%. MWCNTs and Al powders were first mechanically mixed and then ball milled for 3 h, with a ball-to-powder weight ratio of 20:1 and a milling speed of 352 rpm, to uniformly disperse MWCNTs on the surface of Al flakes as obtained. Then, the MWCNT/Al composite powders were cold pressed into a cylinder of 40 mm in diameter by uniaxial pressure of 350 MPa. Subsequently, the green billets were sintered in a vacuum hot pressing (VHP)

unit with a graphite mold. The VHP process involved the following steps: (1) the billets were heated up to 400 °C at the rate of 10 °C/min and then held for 0.5 h for degassing; (2) the billets were further heated up to temperatures range of 570-640 °C and then held for 0.5-6.0 h to induce different interfacial reaction extent, while a uniaxial pressure of 67.7 MPa was applied to promote the consolidation of MWCNT/Al composites according to the previous works [6, 21, 22]. After furnace cooling, the sintered billets were cut into 15×15×2.5 mm plate samples, polished and then cleaned in an ultrasonic cleaner to remove impurities on the surface.

The VHPed MWCNT/Al samples were characterized by the newly developed method (see 3.1 for details ) as well as XRD, RS and TEM for comparison. XRD was performed on an X-Ray diffractometer (XRD-6100, Shimadzu Co. Ltd., Japan), operating at 40 kV/40 mA and using Cu K<sub>α</sub> radiation ( $\lambda=0.15406$  nm). 2 $\theta$  scans were performed between 20 and 90° with a scan speed of 5°/min. Careful scanning was performed in the angle range of 30-37° with a step size of 0.01° and scan time of 2 s per increment to check the presence of Al<sub>4</sub>C<sub>3</sub> (JCPDS file 35-0799). Raman spectra were recorded with a microscopic laser Raman spectrometer (Senterra R200-L, Bruker Co. Ltd, German) in the back-scattering geometry, and by using the 532 nm line of a diode-pumped solid-state laser in the spectral range from 400 to 2000 cm<sup>-1</sup>. An FEI Tecnai G2 transmission electron microscope, operated at 200 kV and equipped with an EDAX energy-dispersive X-ray spectrometry (EDX) detector, was used for high-resolution (HR) TEM characterization. EDX spectrum was recorded in TEM mode by using a focused beam having the size of a few nanometers. TEM thin

foils were prepared by mechanical polishing to reduce sample thickness down to around 30-50  $\mu\text{m}$ . Final ion milling of punched disk samples, having 3 mm in diameter, was carried out by using a Gatan Model 691 precision ion polishing system. Accelerating voltage was set to 5 kV and dual ion sources with milling angles of  $10^\circ$  was employed. Total ion milling time was in the range 2-3 h to reach electron transparency.

### 3. Results and discussion

#### 3.1. The experimental set-up and quantitative characterization method

The newly developed method mainly includes three steps: electrochemical dissolution, gas collection and gas chromatography analysis. As shown in Fig. 1, the measurement is conducted in completely airtight environment using a deliberately designed experimental set-up that integrates separating funnel, sealing flange and electrodes from top to bottom (see Fig. 1b), which is convenient for injecting and draining the electrochemical electrolyte. Sodium hydroxide (NaOH) aqueous solution with a concentration of 4 mol/L is used as the electrolyte and its quantity is adjusted by the separating funnel. Instead of chemical dissolution initially proposed in [15], electrochemical dissolution has been used in order to accelerate the dissolving of the samples. Current density of  $2 \text{ A/cm}^2$  is controlled by a direct current power supply (PS405D). As can be seen in Table 1, it enables the dissolution speed nearly one order of magnitude higher than chemical dissolution. Within 1.0-5.0 h, the sintered MWCNT/Al samples (~1.5 g each) could be completely dissolved in the NaOH



solution while the released CH<sub>4</sub> is purged with pure nitrogen gas. The CH<sub>4</sub>/N<sub>2</sub> is collected in a vacuum bag, and after digestion, injected with a fixed amount (50 ml) of CO gas as a reference for subsequent analysis. Then the gas mixture is passed through a gas chromatograph (GC-2010, Shimadzu Co. Ltd, Japan), which can quantitatively measure the concentration of CH<sub>4</sub> and CO.

The reactions during the electrochemical dissolution of C/Al composites are listed as follows.



According to equation (3), whatever the C/Al composites are, only Al<sub>4</sub>C<sub>3</sub> can react with water to generate CH<sub>4</sub> gas. Thus the reacted carbon, namely the absolute mass of C in Al<sub>4</sub>C<sub>3</sub> or CH<sub>4</sub> can be calculated by the volume of CH<sub>4</sub> released by Al<sub>4</sub>C<sub>3</sub> hydrolysis.

$$m_{\text{C-Al}_4\text{C}_3} = m_{\text{C-CH}_4} = 12 \times V_{\text{CH}_4} / 22.4 \quad (4)$$

If we define the extent of interfacial reaction,  $\eta$ , as the mass ratio of reacted carbon to total carbon in C/Al samples, then it can be deduced from formula (5).

$$\eta = \frac{m_{\text{C-Al}_4\text{C}_3}}{m_{\text{C-C/Al}}} \times 100\% = \frac{12 \times V_{\text{CH}_4} / 22.4}{m_{\text{C/Al}} \times \omega} \times 100\% \quad (5)$$

Where  $V_{\text{CH}_4}$  is the volume of CH<sub>4</sub>,  $m_{\text{C-Al}_4\text{C}_3}$  and  $m_{\text{C-C/Al}}$  are the mass of C in Al<sub>4</sub>C<sub>3</sub> and C/Al sample, respectively. While  $m_{\text{C/Al}}$  is the mass of C/Al sample,  $\omega$  is the

mass fraction of C in C/Al sample, which is measured by a carbon sulfur infrared spectrometer (CSI, CS-206, BaoYing Tech, China).

The interfacial reaction extent of different MWCNT/Al samples is calculated based on formula (5) and the results are plotted in Fig. 2. As expected, the interfacial reaction extent increases with sintering temperature and sintering time.

It was reported that the solubility of CH<sub>4</sub> in 4 mol/L NaOH aqueous solution was about 0.64 mg/100 g at 60 °C [24, 25]. In our case, the possible mass of CH<sub>4</sub> released by the 2.0 wt.% MWCNT/Al (~1.5 g) samples is in the range 0-40 mg. Hence, the measurement error could be caused by residual CH<sub>4</sub> dissolved in the aqueous solution and/or CH<sub>4</sub> remained within connecting conduct, particular in the case of very low Al<sub>4</sub>C<sub>3</sub> content (e.g. the 570°C-2h sample shown in Fig. 2). To reduce the measurement error, the experimental set-up was carefully purged with nitrogen gas after electrochemical dissolution, and the purging gas was collected in the vacuum bag for measurement.

### 3.2. Al<sub>4</sub>C<sub>3</sub> content characterization and comparison with XRD, RS and TEM

Sintering temperature and time are two main factors determining the extent of the Al<sub>4</sub>C<sub>3</sub>-formed interfacial reaction. Higher sintering temperature and longer time always result in more severe reaction [26]. As shown in Fig. 3a, Al (111), (200), (220), (311) and (222) peaks are clearly visible for all the MWCNT/Al samples. Because the content of MWCNTs (2.0 wt.%) and Al<sub>4</sub>C<sub>3</sub> (8.0 wt.% if all the MWCNTs be converted) may be less than the detectability limit of XRD, no C peaks and Al<sub>4</sub>C<sub>3</sub>

peaks are detected by XRD except for in the sample sintered at the highest sintering temperature for the longest time, i.e. at 640 °C for 5 h. As shown in Fig. 3b, the  $\text{Al}_4\text{C}_3$  (101), (012), (009) and (015) peaks only appear in the 640 °C-5 h sample, which corresponds to a very high extent (91%) of interfacial reaction, namely 0.1092 g  $\text{Al}_4\text{C}_3$  (~7.3 wt.%) is formed according to the proposed quantitative method. Similarly, RS peaks of  $\text{Al}_4\text{C}_3$  (494 and 868  $\text{cm}^{-1}$ ) are clearly visible only in the 640 °C-5 h sample. For the samples of lower interfacial reaction extent, however, the RS peaks of MWCNTs display notable broadening/shift in both D-band (1350  $\text{cm}^{-1}$ ) and G-band (1585  $\text{cm}^{-1}$ ) which may suggest the amorphization of MWCNTs and the transformation into  $\text{Al}_4\text{C}_3$  with the increased sintering temperature and time [17, 27]. Typically, the D-band becomes stronger while the G-band becomes weaker after sintering. As a result, the  $I_D/I_G$  ratio increases from 0.46 (MWCNT/Al powders) to 1.08 (570 °C-2 h sample), which indicates the accumulation of structural defects in MWCNTs [27]. Besides, the shift of G-band toward higher frequencies (see in Fig.4a) indicates the amorphization of MWCNTs as reported earlier [17, 27]. Hence, Neither XRD nor RS are suitable for evaluation of low interfacial reaction extent with very low  $\text{Al}_4\text{C}_3$  content, such as in the case of MWCNT/Al samples sintered at 570 °C, 600 °C and 640 °C for 2 h.

As evidenced above, XRD (Fig. 3) and RS (Fig. 4) have poor measurement accuracy and can only be used in the case of a quite high  $\text{Al}_4\text{C}_3$  content, such as the 640 °C-5h sample that contains ~7.3 wt.%  $\text{Al}_4\text{C}_3$ . But when the interfacial reaction extent is quite low such as 5 % in the 600°C-0.5h sample, conventional techniques

like XRD and RS fail to give reasonable results. In contrast to XRD and RS, the proposed quantitative method can detect  $\text{Al}_4\text{C}_3$  content as low as 0.4 wt.%, namely 0.006 g  $\text{Al}_4\text{C}_3$  formed in the 600°C-0.5h sample ~1.5 g in weight, as shown in Fig. 2b. This means that the detectability limit, i.e. the minimum reaction extent could be detected by the proposed quantitative method is 5 %, with a measurement error of  $\pm 3$  % determined by doing the same test for 5 times.

Furthermore, the validity of the proposed quantitative method have been verified by TEM observation. The exemplified TEM results obtained from the 570°C-2h and 640°C-5h (for comparison) samples are shown in Fig. 5. In general, the contrast of the  $\text{Al}_4\text{C}_3$  phase is dependent on its orientation with respect to the incident electron beam. By extensive sample tilting in the angle range of  $\pm 30^\circ$  (tilting limits of our microscope), only five needle-like and/or plate-like morphologies are identified in the 570°C-2h sample (arrowed in Fig. 5a), which can correspond to  $\text{Al}_4\text{C}_3$ . A plate-like  $\text{Al}_4\text{C}_3$  oriented to the [100] direction is further confirmed by HRTEM (Fig. 5c) and EDX (Figs. 5e-g). In the same sample as shown in Fig. 5d, two complete MWCNTs are locally conserved and no interfacial  $\text{Al}_4\text{C}_3$  is visible at the MWCNT/Al interfaces at this scale. Comparatively, a large amount of needle-like and plate-like  $\text{Al}_4\text{C}_3$  compounds are present in Fig. 5b (640°C-6h) having the field of view with the same magnification as in Fig. 5a. Hence, it is confirmed by TEM that the quantitative method remains effective in the range of very low  $\text{Al}_4\text{C}_3$  content, where XRD and RS become invalid.

Finally, the proposed quantitative method also provides access to the kinetics and

reaction activation energy of the  $\text{Al}_4\text{C}_3$ -formed interfacial reaction. Based on parabolic law [28]:

$$dw/dt = K/w \quad (6)$$

$$w^2/2 = Kt + C \quad (7)$$

Considering  $w=0$  when  $t=0$ :

$$w = (2Kt)^{1/2} \quad (8)$$

where  $w$ ,  $K$  and  $t$  are the weight of  $\text{Al}_4\text{C}_3$ , the growth rate constant and the holding time in sintering process, respectively. Moreover, the growth rate constants at different temperatures allow to estimate the activation energy by using subsequent Arrhenius' law [28]

$$K = k \exp(-Q/RT) \quad (9)$$

$$\ln(2K)^{1/2} = \ln(2k)/2 - Q/(2RT) \quad (10)$$

where  $k$ ,  $Q$ , and  $R$  are the constant, activation energy ( $\text{kJ mol}^{-1}$ ) and gas constant ( $8.314 \text{ K}^{-1} \text{ mol}^{-1}$ ), respectively. The activation energy is calculated from the gradient of the linear fitting line in a graph of  $\ln(2K)^{1/2}$  versus  $1/(2RT)$ .

As plotted in Fig. 6a, the gradients of the linear fitting lines  $(2K)^{1/2}$  are 0.1406, 0.4457 and 0.6752 at different sintering temperatures of 570, 600 and 640°C, respectively. The three growth rate constants are then expressed in an Arrhenius plot as shown in Fig. 6b. From the gradient of this plot, the activation energy  $Q$  is determined to be around  $281 \text{ kJ mol}^{-1}$ , which is different from the previously reported

values of  $230 \text{ kJ mol}^{-1}$  for the C/Al (or Al alloys) [29],  $448 \text{ kJ mol}^{-1}$  for the AlN/Al-C [30] and  $349 \text{ kJ mol}^{-1}$  for the  $C_{\text{fiber}}/\text{Al}$  [31], due to the difference in structural integrity and surface defect concentration in different composite systems.

As we know, the milling process may introduce extra structural defects to MWCNTs [32], which makes them more susceptible to react with the Al matrix and leads to a low activation energy. Ci *et al.* [26] have revealed that the MWCNT/Al interfacial reaction occurs stage by stage due to the special structure of MWCNTs. In the first stage, the C atoms at the cap or defect sites preferentially react with Al, and the  $\text{Al}_4\text{C}_3$  can nucleate at these defect places even at a temperature lower than  $500 \text{ }^\circ\text{C}$ . In the second stage, following the consumption of C atoms at the cap or defect sites, the C atoms elsewhere will diffuse through Al matrix towards the nucleus, and then  $\text{Al}_4\text{C}_3$  begin to grow and coarsen. Thus, the value of  $281 \text{ kJ mol}^{-1}$  calculated in this study should be the apparent activation energy in related with these two stages.

#### 4. Summary and conclusions

Although the underlying role of C/Al interfacial reaction and resulted  $\text{Al}_4\text{C}_3$  is still unclear, it has been proved to be a feasible pathway to tailoring the properties of aluminum composites reinforced with carbon nanotube, graphene nanosheet, carbon fiber, diamond/graphite particle. Regarding this, we have developed a method of electrochemical dissolution- $\text{CH}_4$  gas collection-gas chromatography to quantitatively characterize the extent of C/Al interfacial reaction in terms of the  $\text{Al}_4\text{C}_3$  amount formed in the composite. The VHPed MWCNT/Al composites with different  $\text{Al}_4\text{C}_3$  content have been used to validate the effectiveness of this method. As confirmed by

XRD, RS and TEM, the detectability limit of this method is around 5 % with an accuracy of  $\pm 3$  %. And then, with the already known MWCNT/Al interfacial reaction extent vs different sintering temperature/time, the reaction kinetics with an activation energy of  $281 \text{ kJ mol}^{-1}$  was derived. Therefore, the proposed quantitative method supplies a useful tool to optimize the processing and properties of all kinds of C/Al composites via interface design and control, which is a key research area worthy of further in-depth study.

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**Table Captions**

Table 1 Time consumption to dissolve MWCNT/Al samples (~1.5 g each)

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**Figure Captions**

Fig. 1 (a) Schematic diagram and (b) the experimental set-up developed in this work.

Fig. 2 Extent of interfacial reaction measured by the newly developed method in 2.0 wt.% MWCNT/Al samples ~1.5 g in weight: (a) sintered at different temperature and for different time; (b) sintered at 600 °C but for different times (0.5-6.0 h). The weight of the reaction-formed  $\text{Al}_4\text{C}_3$  is given above each data. Note that each data is an average of five measurements and the measurement error is  $\pm 3\%$ .

Fig. 3 (a) XRD patterns of the MWCNT/Al composites sintered at different conditions as shown in Fig. 2(a); (b) careful scanning XRD traces in the angle range of  $30\text{-}37^\circ$  to highlight the (101), (012), (009) and (015) diffraction peaks of the formed  $\text{Al}_4\text{C}_3$  phase.

Fig. 4 (a) Raman spectra of the MWCNT/Al composites sintered at different conditions as shown in Fig. 2(a) and Fig. 3(a); (b) Raman spectra of the MWCNT/Al composites sintered at 600 °C for different times as shown in Fig. 2b. Note that the peaks of D- and G-bands correspond to MWCNTs.

Fig. 5 TEM bright-field images of the MWCNT/Al composites: (a) sintered at 570 °C for 2h; (b) sintered at 640 °C for 5h; (c) HRTEM image of the  $\text{Al}_4\text{C}_3$  compound in the box shown in (a), inset is the FFT pattern corresponding to the [100]  $\text{Al}_4\text{C}_3$  orientation; (d) TEM bright-field image of the MWCNT/Al interfaces, inset is the electron diffraction pattern of the MWCNT; (e)-(g) typical EDX spectra of  $\text{Al}_4\text{C}_3$ , MWCNT,

Al matrix. Arrows in (a) and (b) note the needle-like and plate-like  $\text{Al}_4\text{C}_3$ .

Fig. 6 (a) The amount of reaction-formed  $\text{Al}_4\text{C}_3$  as a function of sintering time at different sintering temperatures of 570, 600 and 640 °C, and (b) the calculated growth constant as a function of sintering temperature to determine the reaction activation energy (see text for more details).

**Table 1**

Method	Chemical dissolution	Electrochemical dissolution			
Current density (A/cm <sup>2</sup> )	0	1	2	3	4
Time (h)	25	5	2	1.5	1

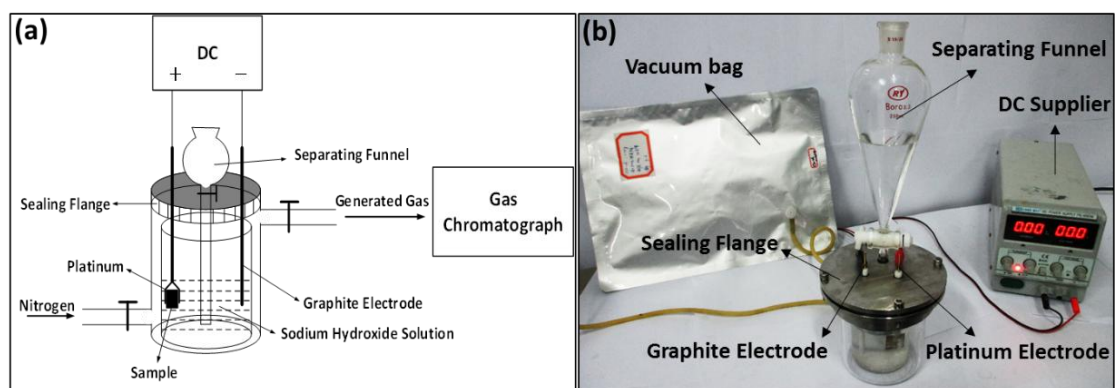


Fig. 1

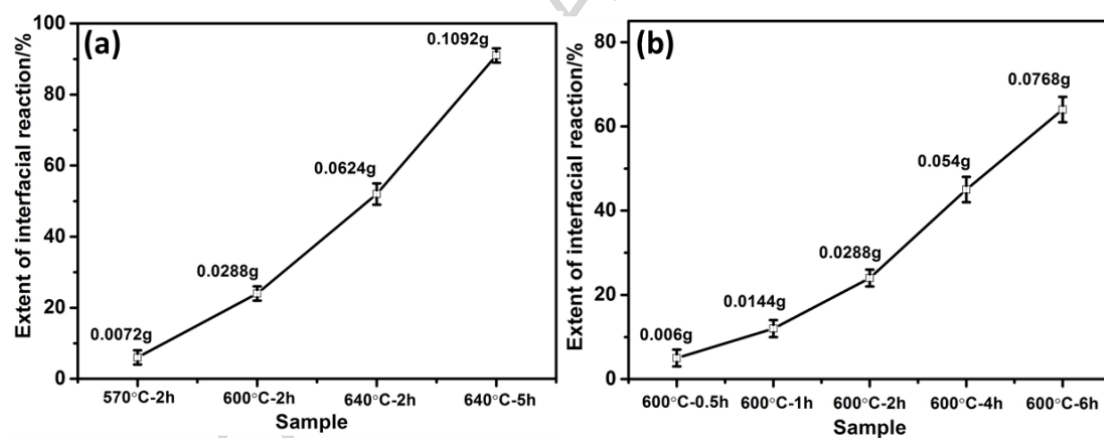


Fig. 2



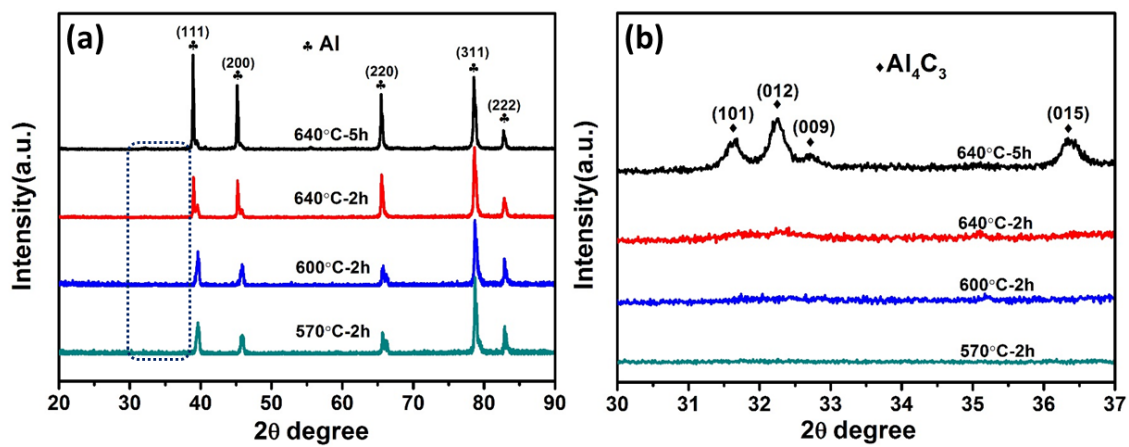


Fig. 3

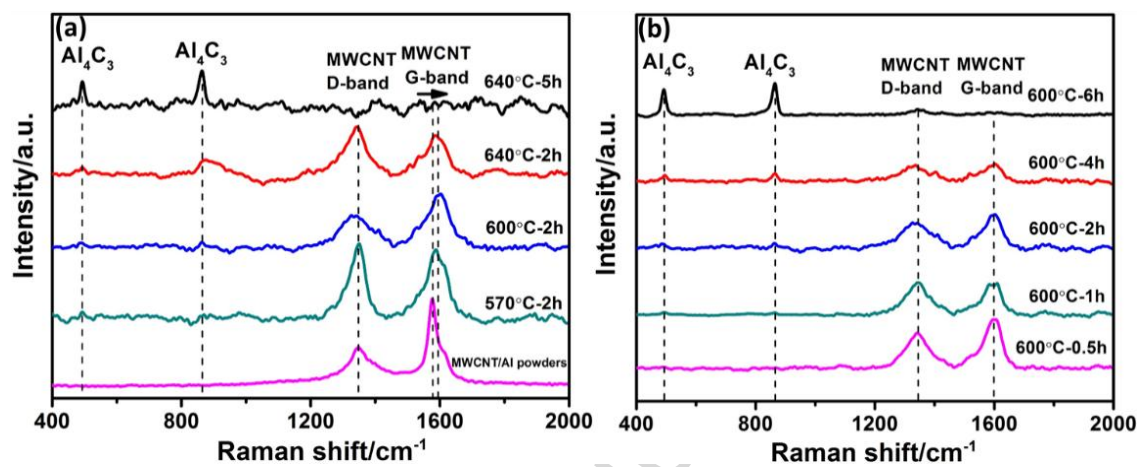


Fig. 4

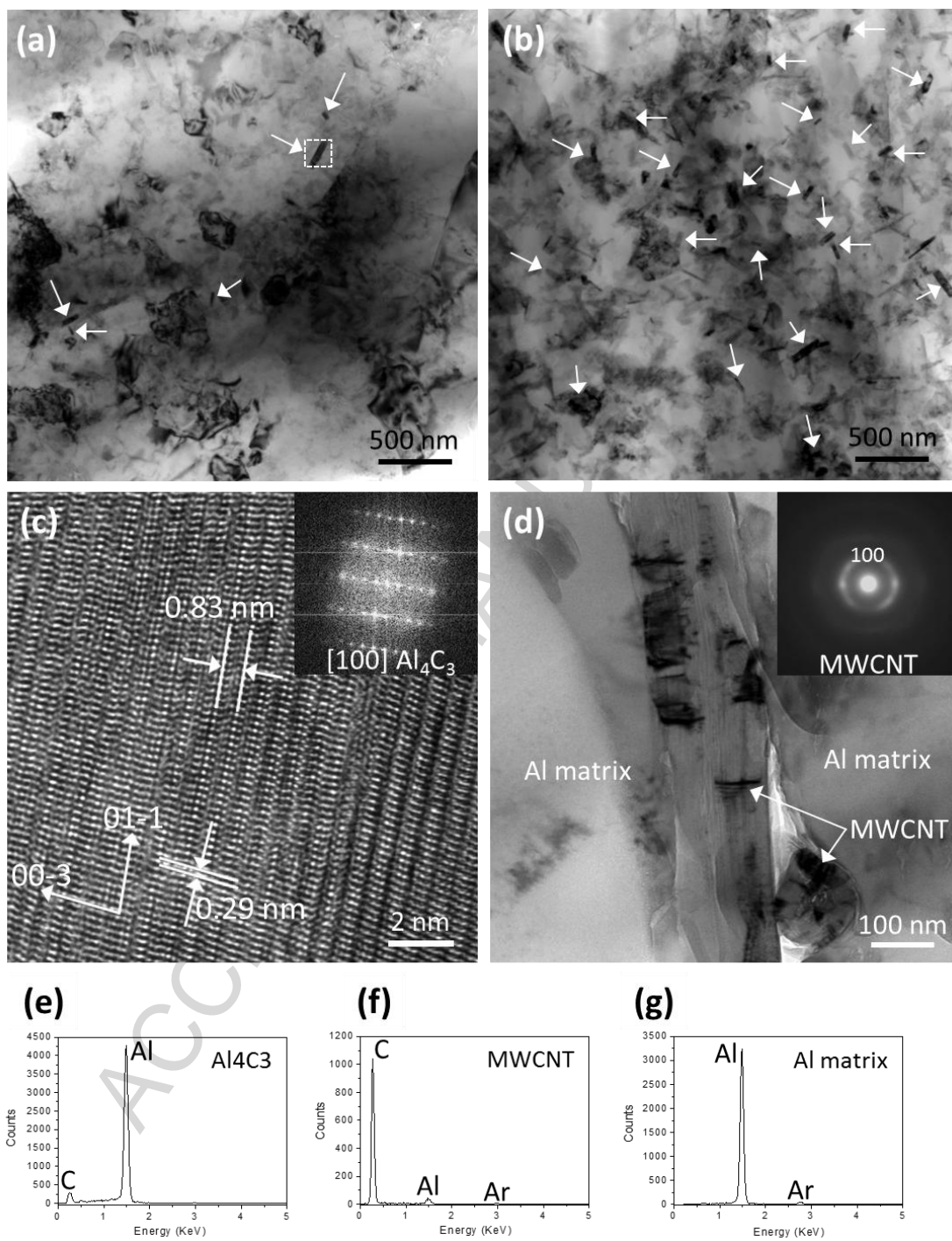


Fig. 5

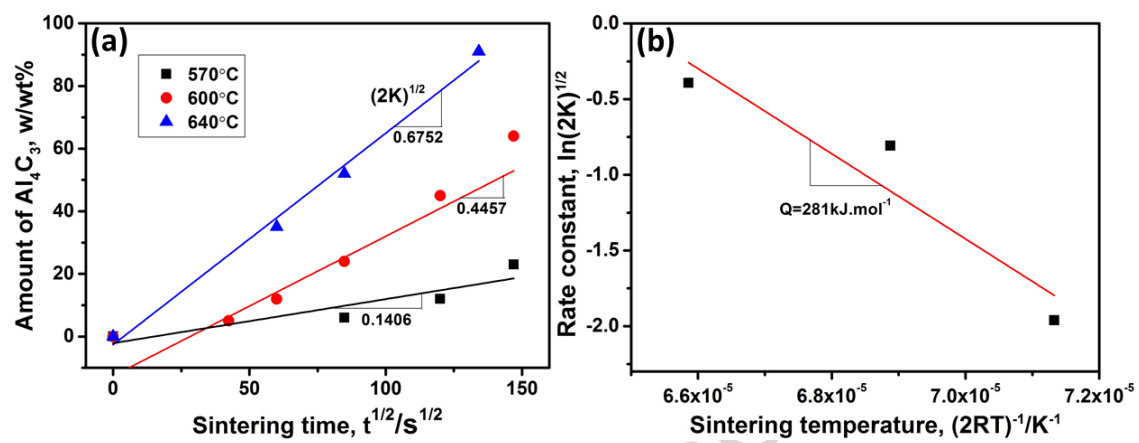


Fig. 6

### Highlights

- A quantitative method to test interfacial reaction of C/Al composite was developed.
- An in-house set-up for the quantitative method was designed.
- The interfacial evolution of MWCNT/Al composite was characterized.
- The kinetics of MWCNT/Al interfacial reaction was analyzed.

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